

Phase Diagram and Magneto-Transport Properties in $\text{Nd}_{1-x}\text{Sr}_x\text{MnO}_3$ Crystals

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Abstract

We have investigated electronic transport and magnetic properties of $\text{Nd}_{1-x}\text{Sr}_x\text{MnO}_3$ crystals with controlled band filling ($0.5 \leq x \leq 0.8$) grown by the floating zone method. The detailed phase diagram of over-doped $\text{Nd}_{1-x}\text{Sr}_x\text{MnO}_3$ was obtained through magnetization, resistivity, and crystal structure measurements. We have found the phase boundary from an insulator with tetragonal symmetry to a metal with pseudocubic one at high temperatures ≈ 450 K. The observed insulator-metal phase transition is attributed to the orbital order-disorder transition.

Key words: phase diagram; orbital-ordering; metal-insulator transition; manganite

Recently, electron-orbital related phenomena such as orbital order-disorder transitions and orbital waves (or orbitons) attract much interest in the $3d$ transition metal oxides [1]. For example, major origin of colossal magnetoresistance in manganites is the magnetic-field-induced destruction of the charge/orbital ordered state. Almost two-dimensional (2D) charge dynamics in the over-doped manganite are caused by the ordering of anisotropic-shaped $d(x^2 - y^2)$ orbital [2]. Experimental evidence for orbiton, which corresponds to the collective excitation of orbital, is lately reported in orbital-ordered states of LaMnO_3 by using Raman scattering [3]. Thus, the orbital degree of freedom is thought to be an underlying key parameter for the physics of the $3d$ transition metal oxides including the manganites. We have previously reported a systematic transformation of various orbital-ordered and -disordered states, accompanying the respective spin-ordering features, in $\text{Nd}_{1-x}\text{Sr}_x\text{MnO}_3$ studied by neutron diffraction measurements [4]. The system investigated here, colossal magnetoresistive $\text{Nd}_{1-x}\text{Sr}_x\text{MnO}_3$, shows up complex phase diagram by changing the carrier kinetic energy with doping level x (see also Fig. 2). In the case of

$x=0.55$, the 2D charge-transport due to $d(x^2 - y^2)$ orbital ordering subsists even above Néel temperature (T_N), above which anisotropic crystal structure is also expected to still remain. Therefore, we have investigated the charge-transport reflecting the orbital state in a wide temperature range. In this paper we report on the temperature-induced melting transition of orbital ordering and propose a revised phase diagram of over-doped $\text{Nd}_{1-x}\text{Sr}_x\text{MnO}_3$ crystals.

$\text{Nd}_{1-x}\text{Sr}_x\text{MnO}_3$ crystals were grown by the floating zone method. The grown crystals were characterized by powder X-ray diffraction measurements. We have confirmed that the grown crystals were single phase without any secondary or impurity phase except for the sample showing a phase separation in low temperature near the phase boundary ($x \sim 0.63$). Measurement of $\rho - T$ curves was performed for the sample heated in a muffle furnace up to 1000 K far above T_N by using standard four-probe method. We have used a calibrated Pt-Pt+13%Rh thermocouple for monitoring temperature. We have not been able to measure the anisotropic transport properties because of a multidomain structure that is not thoroughly eliminated in the present crystal.

We show in Fig. 1 temperature dependence of resis-

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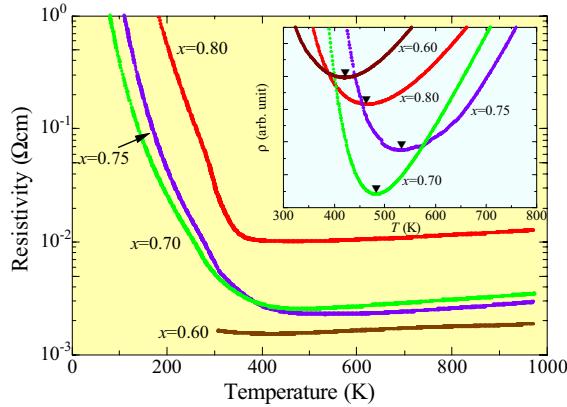


Fig. 1. Temperature dependence of resistivity for $\text{Nd}_{1-x}\text{Sr}_x\text{MnO}_3$ crystals ($x=0.6, 0.7, 0.75$, and 0.8) in zero magnetic field. The inset shows the magnification of the main panel. The phase transition temperature is indicated by an inverted triangle.

tivity for $\text{Nd}_{1-x}\text{Sr}_x\text{MnO}_3$ crystals. In the over-doped manganites with $0.63 \leq x \leq 0.8$, in which the chain-type (*C*-type) antiferromagnetic (AF) insulator is stabilized below T_N (≈ 300 K), resistivity sharply decreases with increasing temperature, and then shows the minimum point (≈ 450 K, depicted in the inset) and gradually rises up. A slight change in activation energy of resistivity has also been detected at T_N . This insulator-metal phase transition is due to the melting transition of orbital ordering. According to the neutron diffraction measurements [5], lattice structural changes occur at respective temperatures corresponding to the insulator-metal transitions: the tetragonal symmetry (*I4/mcm*) in low temperature phase is changed to the pseudocubic symmetry ($\overline{R\bar{3}C}$) in high temperature one. In other words, *c*-axis elongated crystal due to the rod-shaped $d(3z^2 - r^2)$ -type orbital ordering can be transferred to the nearly cubic one due to the spherical orbital, which is the admixture of $d(3z^2 - r^2)$ with $d(x^2 - y^2)$. It should be noted that the orbital and charge ordering at these high temperature regions is not static long-range order but dynamical short-range order or a precursor. We cannot observe a direct evidence of charge- and orbital- ordered state such as a superlattice structure in these samples.

We have also confirmed a similar large drop in resistivity at the orbital-ordering transition temperature of ~ 780 K in the parent LaMnO_3 compound. In the case of LaMnO_3 , $d(3x^2 - r^2)/d(3y^2 - r^2)$ -type orbital ordering was clearly observed by synchrotron radiations [6]. We have concluded that large change in resistivity for the present sample arises from the melting of the orbital ordering by comparing the case of LaMnO_3 .

Figure 2 shows thus obtained phase diagram for $\text{Nd}_{1-x}\text{Sr}_x\text{MnO}_3$ together with the data from Ref. [4]. As reported in Ref. [4], the 2D metallic state with

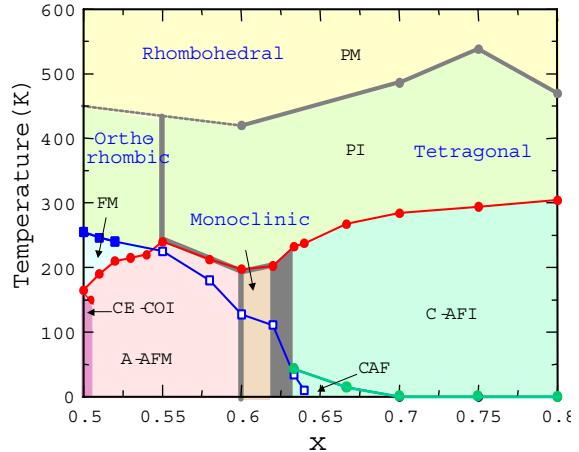


Fig. 2. Electronic, magnetic, and crystallographic phase diagram of $\text{Nd}_{1-x}\text{Sr}_x\text{MnO}_3$ crystal ($0.5 \leq x \leq 0.8$). The abbreviations mean paramagnetic metal (PM), paramagnetic insulator (PI), ferromagnetic metal (FM), *CE*-type charge-ordered insulator (CE-COI), *A*-type antiferromagnetic metal (A-AFM), canted antiferromagnetic insulator (CAF), and *C*-type antiferromagnetic insulator (C-AFI). Open squares mean a paramagnetic Curie temperature. Thick lines are the crystallographic phase boundaries.

layered-type (*A*-type) AF state appears for $0.51 \leq x \leq 0.62$. Doping above $x=0.62$ further alters the magnetic structures to the chain-type. We have found the phase separation near this phase boundary (broad line near at $x=0.625$) between the *A*-type-AF metal with monoclinic crystal symmetry and the *C*-type-AF insulator with tetragonal one. As shown in the figure, spin ordering is decoupled from the orbital degree of freedom similar to the case of the parent material LaMnO_3 . The thick line located around ~ 450 K means the phase boundary between the orbital-ordered insulator with tetragonal symmetry in low temperature phase and orbital-disordered metal with rhombohedral one in high temperature phase.

In conclusion, we have observed the resistive anomaly far above T_N in over-doped manganites, which resulted from the temperature-induced orbital order-disorder transition coupled with the Jahn-Teller lattice distortion. The orbital degree of freedom is thought to be indispensable for understanding this rich phase diagram presented here.

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